AMENDMENTS TO THE CLAIMS

Please cancel all pending claims, *i.e.*, claims 1-18, without prejudice or disclaimer of the subject matter recited therein and please add new claims 19-37 as follows. This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims

Claims 1-18 (Canceled)

19. (new) A magnetron coating system, comprising:

a first coating source;

an auxiliary substrate arranged between the first coating source and an area into which a substrate to be coated is to be received;

a magnetron having a cathode composed of the auxiliary substrate; and

a device structured and arranged to determine an area density of the auxiliary substrate.

- 20. (new) The magnetron coating system according to claim 19, wherein the auxiliary substrate is formed as a cylinder, and the magnetron comprises a rod cathode magnetron.
- 21. (new) The magnetron coating system according to claim 19, wherein the first coating source comprises a planar magnetron.
- 22. (new) The magnetron coating system according to claim 19, wherein the first coating source comprises a shield.

- 23. (new) The magnetron coating system according to claim 19, wherein the device comprises a detection device structured and arranged to determine x-ray fluorescence.
- 24. (new) The magnetron coating system according to claim 19, further comprising additional auxiliary substrates, wherein the magnetron comprises additional cathodes composed of the additional auxiliary substrates.
- 25. (new) A method for depositing thin layers, comprising:

 depositing a layer on an auxiliary substrate via a first coating source;

 coating a substrate via a magnetron having a cathode composed of the auxiliary substrate;

 and

determining an area density of the auxiliary substrate.

- 26. (new) The method of claim 25, wherein a thickness of the layer deposited on the auxiliary substrate is less than 100 nm.
- 27. (new) The method of claim 26, wherein the thickness of the layer deposited on the auxiliary substrate is less than 10 nm.
- 28. (new) The method of claim 25, wherein the layer deposited on the auxiliary substrate comprises a metal layer.

- 29. (new) The method of claim 28, wherein the metal layer comprises an element having a higher mass number than an average mass number of a material of the auxiliary substrate.
 - 30. (new) The method of claim 25, further comprising: operating the first coating source as an other magnetron with inert gas; and operating the magnetron with at least one of the inert gas and reactive gas.
 - 31. (new) The method of claim 30, wherein at least one of the following: the inert gas comprises argon, and the reactive gas comprises at least one of nitrogen, oxygen, and methane.
- 32. (new) The method of claim 25, wherein the area density of the auxiliary substrate is determined after the coating of the substrate.
- 33. (new) The method of claim 25, wherein the determining of the area density of the auxiliary substrate comprises x-ray fluorescence.
- 34. (new) The method of claim 25, further comprising operating the magnetron with DC voltage or pulsed DC voltage.
- 35. (new) The method of claim 25, wherein the cathode comprises several cathodes and the method further comprises operating the magnetron with the several cathodes with a frequency of approximately 10 kHz to approximately 100 kHz.

- 36. (new) The method of claim 25, wherein the coating of the substrate comprises depositing an other layer on the substrate.
 - 37. (new) The method of claim 36, wherein the other layer comprises titanium dioxide.